



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	Rds(ON) Max	ΙD Τ _A = +25°C
-60V	10Ω @ V _{GS} = -5V	-180mA

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- General Purpose Interfacing Switch
- **Power Management Functions**
- Analog Switch

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

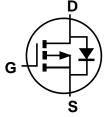
Mechanical Data

- Case: SOT23
- Case Material: UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)

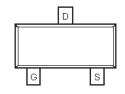




Top View



Equivalent Circuit



Top View

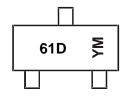
Ordering Information (Note 4)

Part Number	Case	Packaging
DMP610DL-7	SOT23	3,000/Tape & Reel
DMP610DL-13	SOT23	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and < 1000ppm antimony compounds.</p>
 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



61D = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2016		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	D		Ι	I	J	K	L	М	N	0	Р	R
								1				
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	-60	V		
Gate-Source Voltage			Vgss	±30	V
Continuous Drain Current (Note 6) V _{GS} = -5V	I _D	-180 -130	mA		
Maximum Continuous Body Diode Forward Currer	t (Note 6)	Is	-0.5	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 11	%)		I _{DM}	-1.2	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	310	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	405	°C/W
Total Power Dissipation (Note 6)		PD	500	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	251	°C/W
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)				I.		
Drain-Source Breakdown Voltage	BV _{DSS}	-60	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μΑ	V _{DS} = -60V, V _{GS} = 0V
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(TH)	-0.8	_	-2.0	V	$V_{DS} = V_{GS}$, $I_D = -1mA$
Static Drain-Source On-Resistance	R _{DS(ON)}		_	10	Ω	$V_{GS} = -5V, I_{D} = -0.1A$
Forward Transconductance	g FS	_	0.25	_	S	$V_{DS} = -25V$, $I_{D} = -0.1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		24.6	_	pF	
Output Capacitance	Coss	_	4.8	_	pF	$V_{DS} = -25V$, $V_{GS} = 0V$, $f = 1.0MHz$
Reverse Transfer Capacitance	C _{RSS}	_	2.8	_	pF	
Gate Resistance	Rg		2,000	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$
Total Gate Charge (V _{GS} = -4.5V)	QG	_	280	_	рC	
Total Gate Charge (VGS = -10V)	QG		560	_	рC	V _{DS} = -10V. I _D = -100mA
Gate-Source Charge	Qgs	_	90	_	рC	VDS = -10V, ID = -100MA
Gate-Drain Charge	Q _{GD}	_	77	_	рC	
Turn-On Delay Time	tD(ON)	_	2.8	_	ns	
Turn-On Rise Time	t _R	_	2.6	_	ns	$V_{DD} = -30V, I_D = -0.27A,$
Turn-Off Delay Time	tD(OFF)	_	11.1	_	ns	RGEN = 50Ω , VGS = $-10V$
Turn-Off Fall Time	tF	_	7.2	_	ns	

Notes:

Device mounted on FR-4 PCB, with minimum recommended pad layout.
 Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.



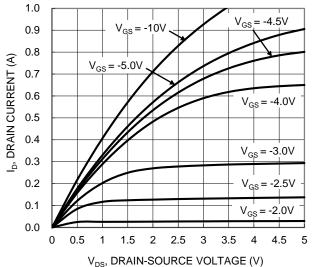


Figure 1. Typical Output Characteristic

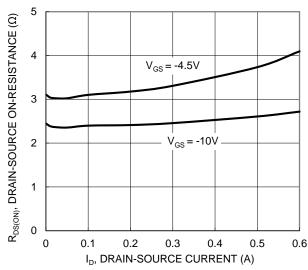


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

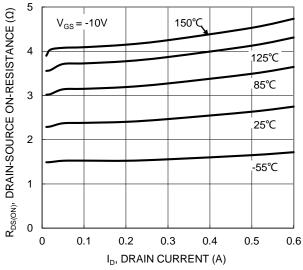


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

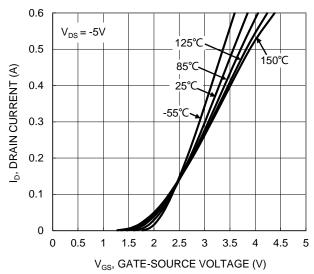
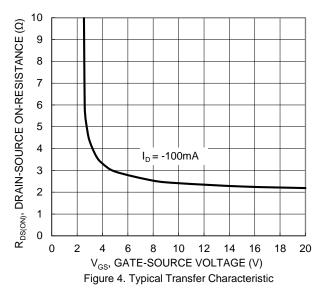


Figure 2. Typical Transfer Characteristic



2 R_{DS(ON)}, DRAIN-SOURCE ON-RESISTANCE (NORMALIZED) 1.8 $V_{GS} = -10V, I_{D} = -200mA$ 1.6 1.4 1.2 $V_{GS} = -4.5 \text{V}, I_{D} = -50 \text{mA}$ 1 8.0 0.6 0.4 0.2 0 50 75 -50 -25 0 25 100 125 150 T_J, JUNCTION TEMPERATURE (°C)

Figure 6. On-Resistance Variation with Temperature



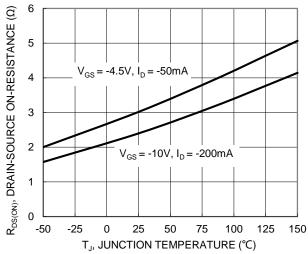
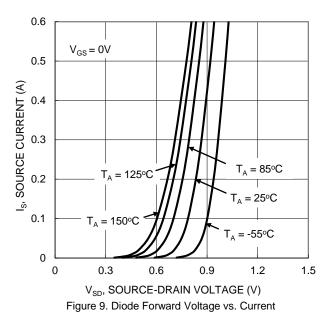


Figure 7. On-Resistance Variation with Temperature



10 9 8 7 $V_{GS}(V)$ 6 5 4 $V_{DS} = -10V, I_{D} = -0.1A$ 3 2 1 0 0.1 0.2 0.3 0.6 0 Q_g (nC)

Figure 11. Gate Charge

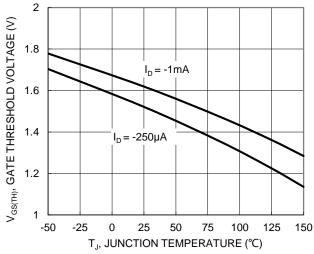


Figure 8. Gate Threshold Variation vs. Junction Temperature

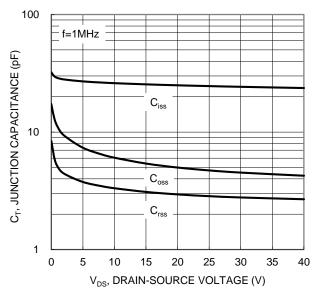


Figure 10. Typical Junction Capacitance



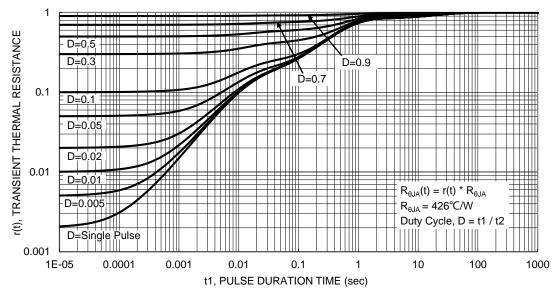


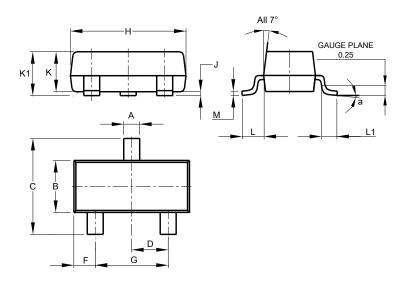
Figure 12. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

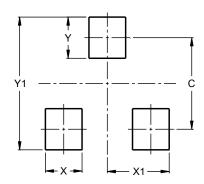


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
C	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
7	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
M	0.085	0.150	0.110				
а	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)			
С	2.0			
X	0.8			
X1	1.35			
Y	0.9			
Y1	2.9			



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